



HDMI 2.0, DisplayPort 1.2 Video Switch

Features

- 4-lane, 1:2 mux/demux that will support RBR, HBR1, or HBR2
- Data rate: 3.4 Gbps to 6.0 Gbps for high data channels
- Supports DDC with HPD channel mux/demux @ HDMI
- Supports 720 Mbps high-speed DP AUX @ DP
- -1.7 dB Insertion Loss for Dx channels @ 3.0 GHz
- -3 dB Bandwidth for Dx channels: 4.8 GHz
- Return loss for Dx channels @ 3.0 GHz: -16 dB
- Low Crosstalk for high speed channels: -25 dB@6.0 Gbps
- Low Off Isolation for high speed channels: -22dB@6.0 Gbps
- Low channel-to-channel skew, 35ps max
- Low Bit-to-Bit Skew, 5ps typ (between '+' and '-' bits)
- V_{DD} Operating Range: 3.3V +/-10%
- ESD Tolerance: 2kV HBM
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts gualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

• Packaging (Pb-free & Green): 42 TQFN (ZHE)

Description

The PI3WVR12412 is a multi-standard video switch with wide voltage range capability. It supports HDMI 2.0, DisplayPort 1.2, and emerging and proprietary standard.

PI3WVR12412 can pass high-speed signals up to 1.2 V peak-topeak differential with a common-mode voltage from 0 to 3.4 V for TMDS signal.

The wide voltage range allow DC-coupled multi-standard operation. Eliminating AC coupling capacitors saves board space and improves signal integrity for dense PCB design. The high speed channels can also pass 0V-3.3V CMOS signals up to 1MHz.

In addition to four high-speed lanes, PI3WVR12412 also switches the DDC and HPD signals or AUX and HPD signals using the DDC/ AUX and HPD channel mux/demux.

Applications

- Routing of HDMI 2.0 video signals with low signal attenuation between source and sink for 4K2K ultra high definition video display and broadcast video equipment.
- Routing of DisplayPort video signals with low signal attenuation between source and sink for PC and monitor.

Notes:

^{1.} No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

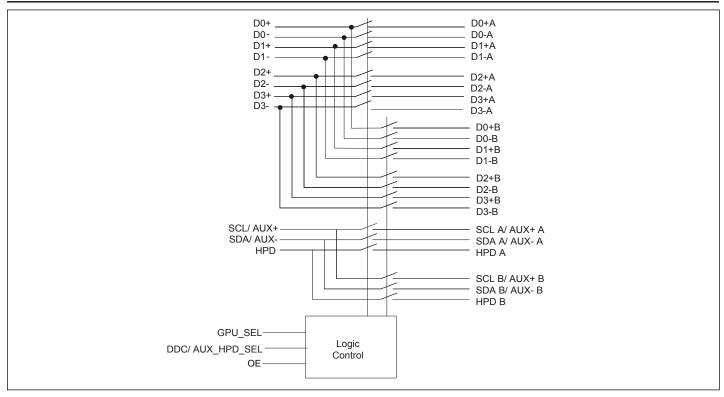
^{2.} See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

^{3.} Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.









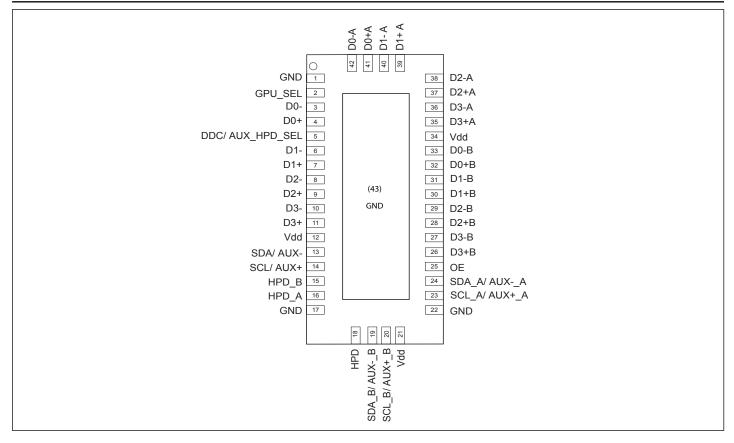
Truth Table

| | Control | | | Switch Funct | ion |
|------|---------|------------------|-------|--------------|-------|
| OE | GPU_SEL | DDC/ AUX_HPD_SEL | D0-D3 | DDC/ AUX | HPD |
| High | Low | Low | А | DDC A/ AUX A | HPD A |
| High | Low | High | А | DDC B/ AUX B | HPD B |
| High | High | Low | В | DDC A/AUX A | HPD A |
| High | High | High | В | DDC B/ AUX B | HPD B |
| Low | X | Х | Hi-Z | Hi-Z | Hi-Z |





Pin Configuration



Pin Description

| Pin# | Pin Name | Signal Type | Description | |
|------|------------------|-------------|---|--|
| 1 | GND | Ground | Ground | |
| 2 | GPU_SEL | Ι | Switch logic control | |
| 3 | D0- | I/O | Negative differential signal 0 for COM port | |
| 4 | D0+ | I/O | Positive differential signal 0 for COM port | |
| 5 | DDC/ AUX_HPD_SEL | Ι | Switch logic control for DDC/ AUX and HPD | |
| 6 | D1- | I/O | Negative differential signal 1 for COM port | |
| 7 | D1+ | I/O | Positive differential signal 1 for COM port | |
| 8 | D2- | I/O | Negative differential signal 2 for COM port | |
| 9 | D2+ | I/O | Positive differential signal 2 for COM port | |
| 10 | D3- | I/O | Negative differential signal 3 for COM port | |
| 11 | D3+ | I/O | Positive differential signal 3 for COM port | |
| 12 | VDD | Power | 3.3V +/-10% power supply | |
| 13 | SDA/ AUX- | I/O | SDA signal for DDC COM port, or negative differential signal for AUX COM port | |





Pin Description Cont.

| Pin# | Pin Name | Signal Type | Description |
|------|---------------|-------------|---|
| 14 | SCL/ AUX+ | I/O | SCLl signal for DDC COM port, or positive differential signal for AUX COM port |
| 15 | HPD_B | I/O | HPD for port B |
| 16 | HPD_A | I/O | HPD for port A |
| 17 | GND | Ground | Ground |
| 18 | HPD | I/O | HPD for COM port |
| 19 | SDA_B/ AUXB | I/O | SDA signal for DDC, port B, or negative differential signal for AUX COM port |
| 20 | SCL_B/ AUX+_B | I/O | SCL signal for DDC, port B, or positive differential signal for AUX COM port |
| 21 | VDD | Power | 3.3V +/-10% power supply |
| 22 | GND | Ground | Ground |
| 23 | SCL_A/ AUX+_A | I/O | SCL signal for DDC, port A, or positive differential signal for AUX COM port |
| 24 | SDA_A/ AUXA | I/O | SDA signal for DDC, port A, or negative differential signal for AUX COM port |
| 25 | OE | I | Output enable. if OE is high, IC is enabled. if OE is low, IC is power down and all I/Os are Hi-Z |
| 26 | D3+B | I/O | Positive differential signal 3 for portB |
| 27 | D3-B | I/O | Negative differential signal 3 for portB |
| 28 | D2+B | I/O | Positive differential signal 2 for portB |
| 29 | D2-B | I/O | Negative differential signal 2 for portB |
| 30 | D1+B | I/O | Positive differential signal 1 for portB |
| 31 | D1-B | I/O | Negative differential signal 1 for portB |
| 32 | D0+B | I/O | Positive differential signal 0 for portB |
| 33 | D0-B | I/O | Negative differential signal 0 for portB |
| 34 | VDD | Power | 3.3V +/-10% power supply |
| 35 | D3+A | I/O | Positive differential signal 3 for port A |
| 36 | D3-A | I/O | Negative differential signal 3 for port A |
| 37 | D2+A | I/O | Positive differential signal 2 for port A |
| 38 | D2-A | I/O | Negative differential signal 2 for port A |
| 39 | D1+A | I/O | Positive differential signal 1 for port A |
| 40 | D1-A | I/O | Negative differential signal 1 for port A |
| 41 | D0+A | I/O | Positive differential signal 0 for port A |
| 42 | D0-A | I/O | Negative differential signal 0 for port A |
| 43 | Center pad | Ground | Ground |





Maximum Ratings

| (Above which useful life may be impaired. For user guidelines, not test | |
|---|--|
| Storage Temperature65°C to +150°C | Note: |
| Junction Temperature | Stresses greater MUM RATINGS |
| Supply Voltage to Ground Potential0.5V to +4.2V | the device. This is |
| High Speed Data Channel0.5V to 3.8V | |
| HPD_x, SDA_x, SCL_x0.5V to 5.5V | above those indica |
| DC Input Voltage0.5V to V _{DD} | specification is not mum rating condi |
| DC Output Current120mA | reliability. |
| Power Dissipation | |
| | 1 |

than those listed under MAXI-S may cause permanent damage to is a stress rating only and functional device at these or any other conditions ated in the operational sections of this ot implied. Exposure to absolute maxilitions for extended periods may affect

DC Electrical Characteristics for Switching over Operating Range

 $(T_A = -40^{\circ}C \text{ to } +105^{\circ}C, V_{DD} = 3.3V \pm 10\%)$

| Parameter | Description | Test Conditions ⁽¹⁾ | Min. | Typ. (2) | Max. | Units | |
|--------------------------|--|---|------|-----------------|------|-------|--|
| V _{IH} | Input HIGH Voltage (SEL & OE) | Guaranteed HIGH level | 1.5 | | | | |
| V _{IL} | Input LOW Voltage (SEL & OE) | Guaranteed LOW level | | | 0.75 | | |
| V _{IK} | Clamp Diode Voltage (HS Channel) | V_{DD} = Max., I_{IN} = -18mA | | -1.6V | -1.8 | V | |
| V _{IK} | Clamp Diode Voltage (DDC/ AUX, Cntrl) | V_{DD} = Max., I_{IN} = -18mA | | -0.7 | -1.5 | | |
| I _{IH} | Input HIGH Current | V_{DD} = Max., V_{IN} = V_{DD} | | | ±5 | | |
| I _{IL} | Input LOW Current | V _{DD} = Max., V _{IN} = GND | | | ±5 | μA | |
| I _{OFF_SB} | I/O leakage when part is off for side- band signals only (DDC/ AUX, HPD) | $V_{DD} = 0V$, $V_{INPUT} = 0V$ to 3.6V | | | 20 | μ23 | |
| R _{ON_HS} | On resistance between input to out- put for high speed signals | $\begin{split} V_{\rm INPUT,cm} &= 0 V \text{ to } 3.4 V, \\ V_{\rm INPUT,diff} &< 1.2 V_{p\text{-}p,diff}, \\ V_{\rm DD} &= 3.0 V, I_{\rm INPUT} = 20 \text{mA} \end{split}$ | | 11 | | Ω | |
| R _{ON_DDC/ AUX} | On resistance between input to output for side-band signals (DDC/ AUX) | V_{DD} = 3.0V, V_{INPUT} = 0 to 3.3V, I_{INPUT} = 20mA | | 7 | | Ω | |
| R _{ON_HPD} | On resistance between input to output for HPD channel | V_{DD} = 3.0V, V_{INPUT} = 0 to 3.0V, I_{INPUT} = 20mA | | 7 | | Ω | |
| VDDC/ AUX_SS | Signal Swing Tolerance in DDC/ AUX path | V _{DD} = 3.0V | -0.5 | | 5.5 | V | |
| V _{HPD_I} | Input voltage on HPD path | | | | 5.5 | V | |
| V _{HPD_O} | Output voltage tolerance on HPD path | HPD input from 3.3V to 5.25V | | 3.3 | 3.6 | V | |





Power Supply Characteristics

 $(T_A = -40^{\circ}C \text{ to } +105^{\circ}C)$

| Parameter | Description | Test Conditions ⁽¹⁾ | Min. | Typ. (2) | Max. | Units |
|---------------------|--------------------------------|--|------|-----------------|------|-------|
| I _{DD} | Power Supply Current | V_{DD} = 3.3V, V_{IN} = GND or V_{DD} | | 1 | 3 | mA |
| I _{DD,Off} | Power Supply Current, Disabled | V_{DD} = 3.3V, V_{IN} = GND or V_{DD} , V_{OE} < V_{IL} | | 1 | 50 | μΑ |

Note:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at V_{DD} = 3.3V, T_A = 25°C ambient and maximum loading.

Dynamic Electrical Characteristics over Operating Range

 $(T_A = -40^{\circ} \text{ to } +105^{\circ}\text{C}, V_{DD} = 3.3\text{V} \pm 10\%)$

| Parameter | Description | Test Conditions | (1) | Min. | Typ. ⁽²⁾ | Max. | Units |
|-------------------|--|--------------------------|--------------|------|----------------------------|-------|-----------|
| | | | f = 3.0 GHz | | -25 | -22 | |
| v | Crosstalk on High Speed | See Fig. 1 for | f = 2.7 GHz | | -28 | -25 | |
| X _{TALK} | Channels | Measurement Setup | f = 1.7 GHz | | -31 | -28 | |
| | | r | f = 1.35 GHz | | -32 | -28 | 10 |
| | | See Fig. 2 for | f = 3.0 GHz | | -22 | -20 | - dB - |
| 0 | OFF Isolation on High Speed Channels | Measurement | f = 2.7 GHz | | -22 | -20 | |
| O _{IRR} | | Setup | f = 1.7 GHz | | -29 | -26 | |
| | | | f = 1.35 GHz | | -30 | -27 | |
| T | Differential Insertion Loss on | @3.0 GHz (see figure 3) | | -2.0 | -1.7 | | dB |
| I _{LOSS} | High Speed Channels | @5.4 Gbps (see figure 3) | | -2.0 | -1.7 | | |
| D | Differential Return Loss on | @ 3.0 GHz (6.0Gbps) | | | -16.0 | -14 | dB |
| R _{loss} | high speed channels | @ 2.7 GHz (5.4Gbps) | | | -14.0 | -12.5 | |
| BW_Dx± | Bandwidth -3dB for Main high speed path (Dx±) | See figure 3 | | 3.7 | 4.8 | | GHz |
| BW_DDC/ AUX/ HPD | -3dB BW for DDC/ AUX and HPD signals | See figure 3 | | 1.35 | 1.5 | | GHz |

Note:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at V_{DD} = 3.3V, T_A = 25°C ambient and maximum loading.





Switching Characteristics $(T_A = -40^{\circ} \text{ to } +105^{\circ}\text{C}, V_{DD} = 3.3\text{V}\pm10\%)$

| Parameter | Description | Min. | Тур. | Max. | Units |
|--------------------|---|------|------|------|-------|
| T _{pd} | Propagation delay (input pin to output pin) on all channels | | 80 | | ps |
| t _{b-b} | Bit-to-bit skew within the same differential pair of Dx± channels | | 5 | 7 | ps |
| t _{ch-ch} | Channel-to-channel skew of Dx± channels | | | 35 | ps |
| Tsw a-b | Time it takes to switch from port A to port B | | | 0.1 | us |
| Tsw b-a | Time it takes to switch from port B to port A | | | 0.1 | us |
| Tstartup | V _{DD} valid to channel enable | | | 10 | us |
| Twakeup | Enabling output by changing OE from low to High | | | 10 | us |

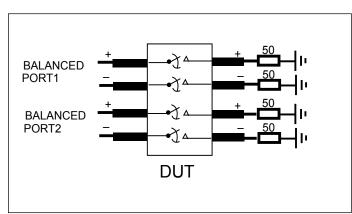


Figure 1. Crosstalk Setup

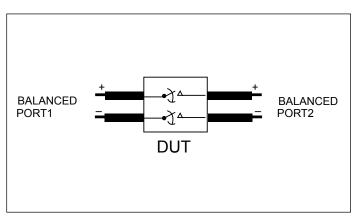


Figure 3. Differential Insertion Loss

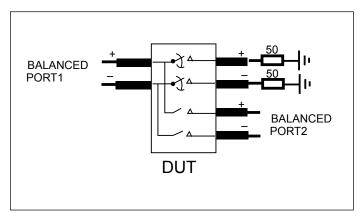
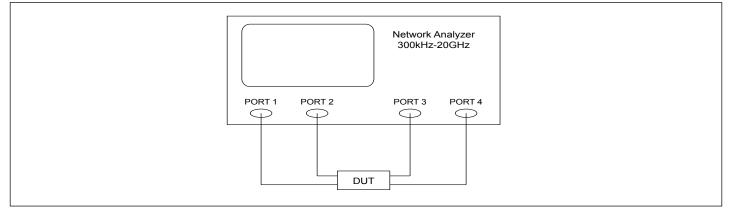


Figure 2. Off-isolation Setup





Test Circuit for Dynamic Electrical Characteristics



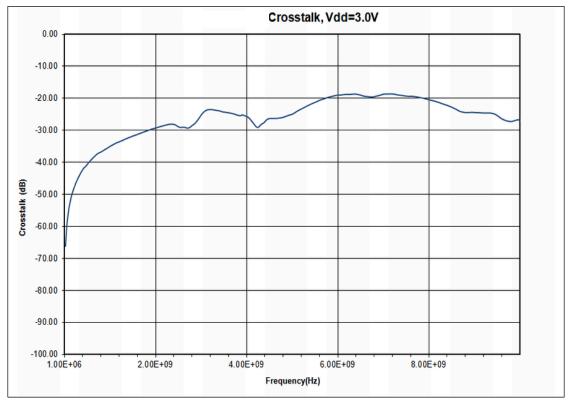


Figure 4. Crosstalk





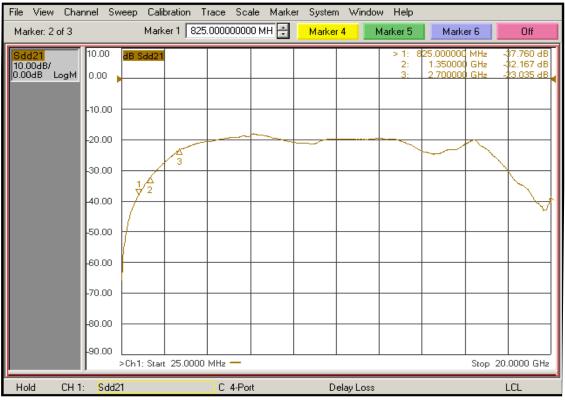


Figure 5. Off Isolation



Figure 6. Insertion Loss







Figure 7. Return Loss

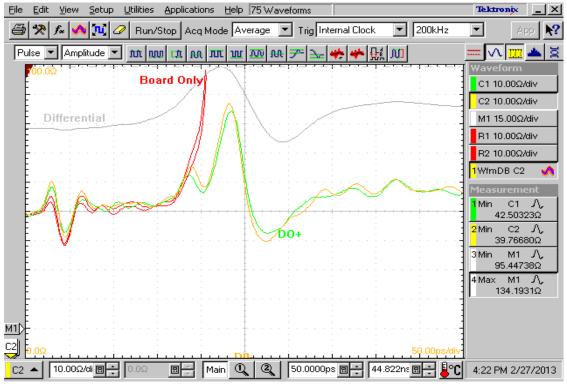
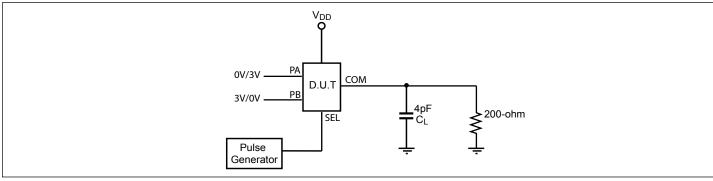


Figure 8. TDR Channel D0, VDD=3.0V, 25C





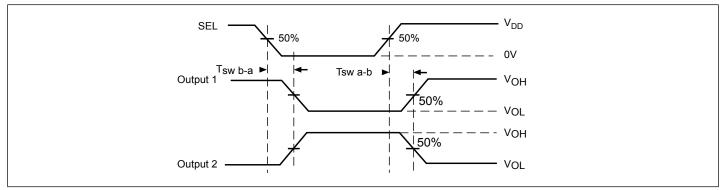
Test Circuit for Electrical Characteristics⁽¹⁻⁴⁾



Notes:

- 1. C_L = Load capacitance: includes jig and probe capacitance.
- 2. R_{T} = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator
- 3. All input impulses are supplied by generators having the following characteristics: PRR \leq MHz, $Z_O = 50\Omega$, $t_R \leq 2.5$ ns, $t_F \leq 2.5$ ns.
- 4. The outputs are measured one at a time with one transition per measurement.

Switching Waveforms



Voltage Waveforms for Select Timing

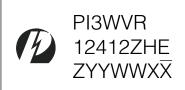
Test Condition

| Output 1 Test Condition | Output 2 Test Condition |
|-------------------------|-------------------------|
| PA = Low | PA = High |
| PB = High | PB = Low |





Part Marking



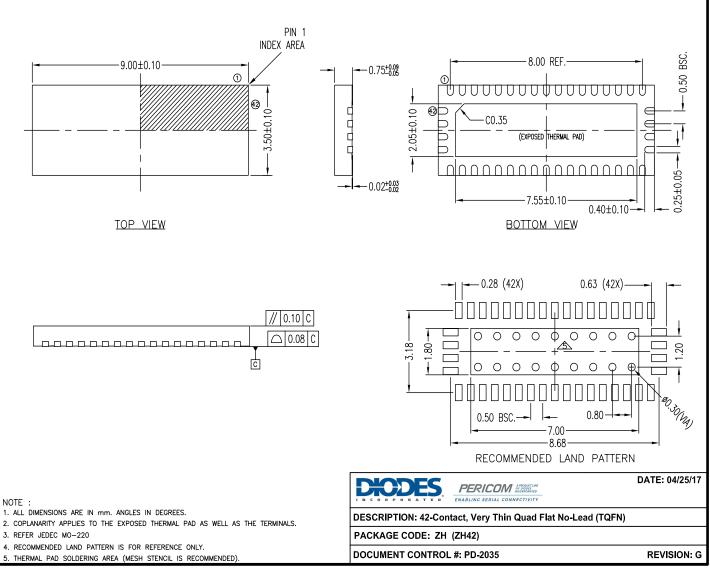
Z: Die Rev YY: Year WW: Workweek 1st X: Assembly Site Code 2nd X: Fab Site Code





Packaging Mechanical

42-TQFN (ZH)



17-0266

For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

| Ordering Code | Package Code | Package Description |
|-----------------|--------------|--|
| PI3WVR12412ZHEX | ZH | 42-contact, Very Thin Quad Flat No-Lead (TQFN) |

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm

antimony compounds.

4. E = Pb-free and Green

5. X suffix = Tape/Reel





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